

Form PTO-1449  <b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b>  <i>(Use several sheets if necessary)</i>				Docket Number (Optional) <b>3259.1US (91-473.02 RE)</b>		Application Number <b>Not Yet Assigned</b>	
				Applicant <b>Dennison et al.</b>			
				Filing Date <b>December 12, 2001</b>		Group Art Unit <b>Unknown</b>	

  

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
TN	4,432,799	02/1984	Salazar			
TN	4,671,851	06/1987	Beyer et al.			
TN	4,785,337	11/1988	Kenney			
TN	4,877,750	10/1989	Okumura			
TN	4,944,836	07/1990	Beyer et al.			
TN	5,045,899	09/1991	Arimoto et al.			
TN	5,150,276	09/1992	Gonzalez et al.			
TN	<del>5,162,248</del>	<del>11/1992</del>	<del>Dennison et al.</del>	<del>  </del>	<del>  </del>	
TN	5,162,248	11/1992	Dennison et al.			
TN	5,185,282	02/1993	Lee et al.			
TN	5,313,089	05/1994	Jones, Jr.			
TN	5,364,809	11/1994	Kwon et al.			

  

FOREIGN PATENT DOCUMENTS							
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
TN	0286270	12/1987	JP				
TN	0074752	03/1989	JP				
TN	0094554	04/1990	JP				

  

OTHER DOCUMENTS		(Including Author, Title, Date, Pertinent Pages, Etc.)
TN		"Stacked Capacitor DRAM Cell with Vertical Fins," IBM TDB, Jul. 1990, pp. 245-247.
TN		Kaga, T., et al., "Crown-Shaped Stacked-Capacitor Cell for 1.5-V Operation 64 Mb Dram's", <u>IEEE Transactions on Electron Devices</u> , vol. 38, No. 2, Feb. 1991, pp. 255-261.
TN		Shinmura, N., et al., "A Stacked Capacitor Cell with Ring Structure", <u>Extended abstracts of the 22<sup>nd</sup> International Conference on Solid State Devices</u> , pp.833-836, 1990.

  

EXAMINER  <div style="text-align: center; font-family: cursive;">T. NGUYEN</div>	DATE CONSIDERED  <div style="text-align: center; font-family: cursive;">4/17/03</div>
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

 826 U.S. PTO  
 10/020741  
 12/12/01